

# Texas Microelectronics Corporation

# High Temperature Static RAM, 2 Megabit (128K X 16)

#### **FEATURES**

- Operation to 200°C
- Single 2.7V ~ 5.5V power supply
- Asynchronous Operation
- Low power consumption
- All outputs TTL compatible
- · Completely static memory
- Tri-state output
- Popular 50-pin PGA footprint

#### **APPLICATIONS**

- High temperature Digital System applications
- Down hole applications
- Avionics
- Automotive applications

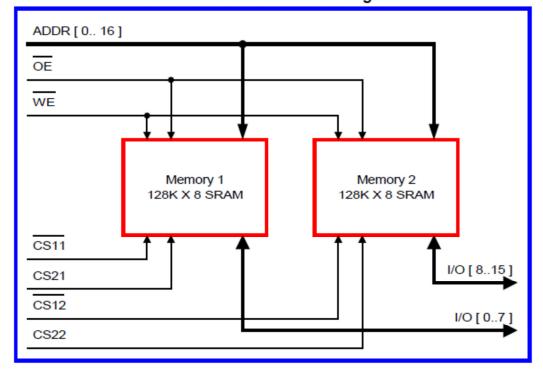
#### **DESCRIPTION**

The TX5304A is a CMOS static RAM organized as  $131,072 \times 16$ -bit words. The device is packaged in a proprietary 50-pin ceramic PGA package employing the 5 x 10 pin footprint with a pitch of 0.1 inch. Powered by a single  $2.7V \sim 5 V$  supply, the unit offers low standby power dissipation and is suitable for battery backup systems. Output lines are tri-stated; power consumption can be minimized through use of the data retention mode.

The TX5304A is composed of two individual SRAM modules, each with 128K x 8-bit memory. Each module has private enable/select lines permitting store/ access of either 8-bit or 16-bit data.

The TX5304A operates from a single power supply of 2.7V  $\sim$  5.5V and all inputs and outputs are fully TTL compatible. The Tx5304A is designed for use in systems operating in very high temperature environments.

## TX5304 Functional Block Diagram



# **TX5304A -- Specifications**

## **Absolute Maximum Ratings\***

Parameter	Symbol	Value	Unit
Supply Voltage relative to V <sub>ss</sub>	V <sub>cc</sub>	-0.5 to + 5.5	V
Voltage on any pin relative to $V_{ss}$	$V_{T}$	-0.5 to Vcc + 0.5	V
Operating Temperature Range	T <sub>opr</sub>	0 to + 200	°C
Storage Temperature Range	$T_{stg}$	-55 to + 200	°C
DC Output Current	l <sub>out</sub>	50	mA

<sup>\*</sup>Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

## **Recommended DC Operating Conditions**

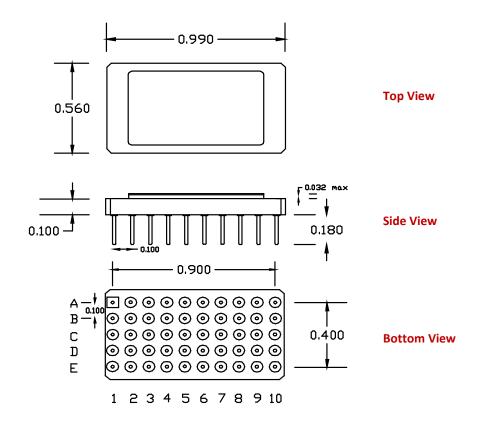
Parameter	Symbol	Min	Max	Unit
Supply Voltage	V <sub>cc</sub>	2.7	5.5	V
Ground Voltage	$V_{ss}$	0.0	0.0	V
Input High Voltage	V <sub>IH</sub>	2.4	V <sub>CC</sub> + 0.2	V
Input Low Voltage	V <sub>IL</sub>	-0.2	0.6	V

#### **DC Electrical Characteristics:**

Parameter	Symbol	Value (typ)	Unit
Input Leakage Current, $V_{CC} \ge V_{IN} \ge V_{SS}$	ILI	2.0	μΑ
Output Leakage Current	I <sub>LO</sub>	2.0	μΑ
Operating Supply Current	I <sub>cc</sub>	60	mA
Standby Supply Current	I <sub>SB1</sub>	1.0	mA
Data Retention Supply Current, V <sub>cc</sub> = 3.0	I <sub>DR</sub>	0.2	μΑ
$V_{cc} = 2.0$	I <sub>DR</sub>	0.2	μΑ
Output Voltage Low	V <sub>OL</sub>	0.4	V
Output Voltage High	V <sub>OH</sub>	2.4	V
V <sub>cc</sub> for data retention	$V_{DR}$	1.5	V
Chip deselect to data retention time	t <sub>CDR</sub>	0	ns
Read Cycle Time	t <sub>RC</sub>	70	ns
Write Cycle Time	t <sub>wc</sub>	70	ns
Input Capacitance	C <sub>IN</sub>	6	pF
Input/Output Capacitance	C <sub>I/O</sub>	8	pF

# **TX5304A Package Information**

TRUTH TAB	LE	For 128K x 16 bit operation				
Mode	CS21/CS22	CS11/CS12	*WE	*OE	I/O Pin Supp	oly Current
Not Selected Not Selected Output Disable Read Write	L X H H	X H L L	X X H H L	X X H L	High-Z High-Z High-Z Data Output Data Input	Standby Standby Active Active Active
H = High Voltage, L = Low Voltage, X = Don't Care						



# **TX5304A Package Pin Information**

	A	В	С	D	E
1	N.C.	N.C.	N.C.	N.C.	CS12
2	Vss	N.C.	N.C.	CS22	Vcc
3	N.C.	A16	WE	CS21	A15
4	A14	A12	A7	A8	A13
5	A6	A5	<del>OE</del>	A11	A9
6	A4	A3	A2	CS11	A10
7	A1	A0	I/O13	I/O12	I/O11
8	I/O10	1/09	1/08	I/O15	I/O14
9	Vss	I/O1	I/O3	1/05	Vcc
10	1/00	1/02	1/04	1/06	1/07

## **WARNING! Static Sensitive Device.**

The TX5304A is a hybrid network that includes several sensitive components. These components can be damaged or destroyed by discharge of static electricity. The discharge of static electricity is commonly referred to as Electrostatic Discharge (ESD).

The TX5304A can be protected from ESD by the following common procedures used with discrete semiconductors, namely:

- 1. Always store units in closed conductive containers
- 2. All personnel that handle units must wear static dissipative outer garments and must be electrically grounded
- 3. Always use a grounded soldering iron when making electrical connections
- 4. Worktables must have grounded dissipative covering.

ESD can cause subtle problems that have longer term, damaging affect.